

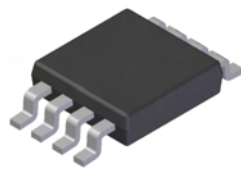
Features

- Low On-Resistance
 - 14mΩ @ $V_{GS} = -20V$
 - 18mΩ @ $V_{GS} = -10V$
 - 36mΩ @ $V_{GS} = -4.5V$
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 2)**
- "Green" Device (Note 4)**
- Qualified to AEC-Q101 Standards for High Reliability**

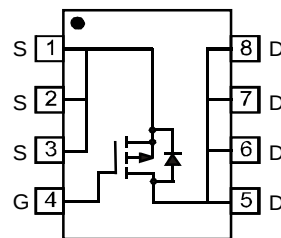
Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram
- Terminals: Finish - Matte Tin annealed over Copper lead frame.
Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.072 grams (approximate)

SO-8



TOP VIEW


 TOP VIEW
Internal Schematic

Maximum Ratings @ $T_A = 25^\circ C$ unless otherwise specified

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	-30	V
Gate-Source Voltage			V_{GSS}	±25	V
Drain Current (Note 1)	Steady State	$T_A = 25^{\circ}C$	I_D	-11	A
		$T_A = 70^{\circ}C$		-8	
Pulsed Drain Current (Note 3)			I_{DM}	-80	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	P_D	2.0	W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	60	$^\circ C/W$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ C$

- Notes:
- Device mounted on 1 in.² FR-4 board with 2 oz. Copper, in a still-air environment with $T_A = 25^\circ C$.
 - No purposefully added lead.
 - Repetitive rating, pulse width limited by junction temperature.
 - Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)						
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	—	V	V _{GS} = 0V, I _D = -250μA
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-1	μA	V _{DS} = -30V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	±100 ±800	nA	V _{GS} = ±20V, V _{DS} = 0V V _{GS} = ±25V, V _{DS} = 0V
ON CHARACTERISTICS (Note 5)						
Gate Threshold Voltage	V _{GS(th)}	-1	—	-2	V	V _{DS} = V _{GS} , I _D = -250μA
Static Drain-Source On-Resistance	R _{DS(on)}	—	11 15 27	14 18 36	mΩ	V _{GS} = -20V, I _D = -11A V _{GS} = -10V, I _D = -8A V _{GS} = -4.5V, I _D = -5A
Forward Transconductance	g _{fs}	—	12	—	S	V _{DS} = -10V, I _D = -12A
Diode Forward Voltage (Note 5)	V _{SD}	-0.5	—	-1.1	V	V _{GS} = 0V, I _S = -2A
DYNAMIC CHARACTERISTICS						
Input Capacitance	C _{iss}	—	1655	—	pF	V _{DS} = -20V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	C _{oss}	—	286	—	pF	
Reverse Transfer Capacitance	C _{rss}	—	240	—	pF	
Gate Resistance	R _G	—	2.3	—	Ω	V _{GS} = 0V, V _{DS} = 0V, f = MHz
SWITCHING CHARACTERISTICS						
Total Gate Charge	Q _g	—	15.3 30.7	—	nC	V _{DS} = -15V, V _{GS} = -4.5V, I _D = -8A V _{DS} = -15V, V _{GS} = -10V, I _D = -8A
Gate-Source Charge	Q _{gs}	—	3.5	—		V _{DS} = -15V, V _{GS} = -10V, I _D = -8A
Gate-Drain Charge	Q _{gd}	—	7.9	—		V _{DS} = -15V, V _{GS} = -10V, I _D = -8A
Turn-On Delay Time	t _{d(on)}	—	5.1	—	ns	V _{GS} = -10V, V _{DS} = -15V, R _D = 15Ω, R _G = 6Ω
Rise Time	t _r	—	8	—		
Turn-Off Delay Time	t _{d(off)}	—	46	—		
Fall Time	t _f	—	30	—		

Notes: 5. Short duration pulse test used to minimize self-heating effect.

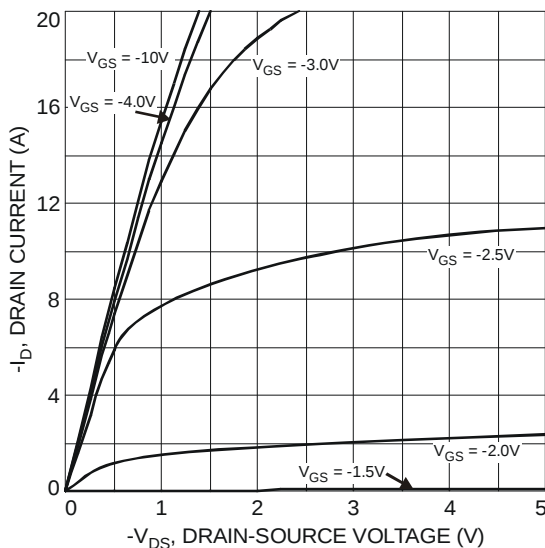


Fig. 1 Typical Output Characteristic

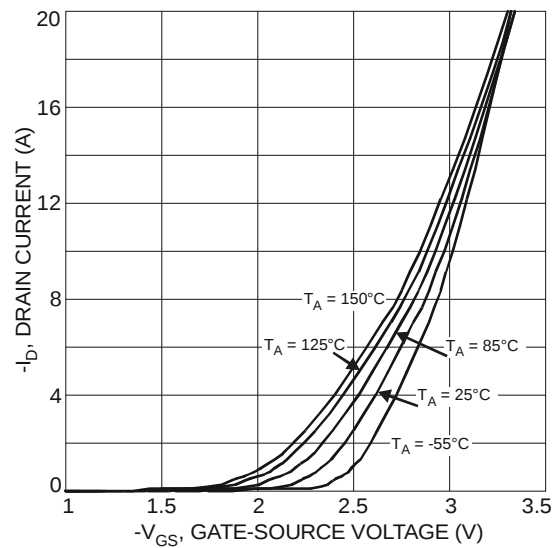


Fig. 2 Typical Transfer Characteristic

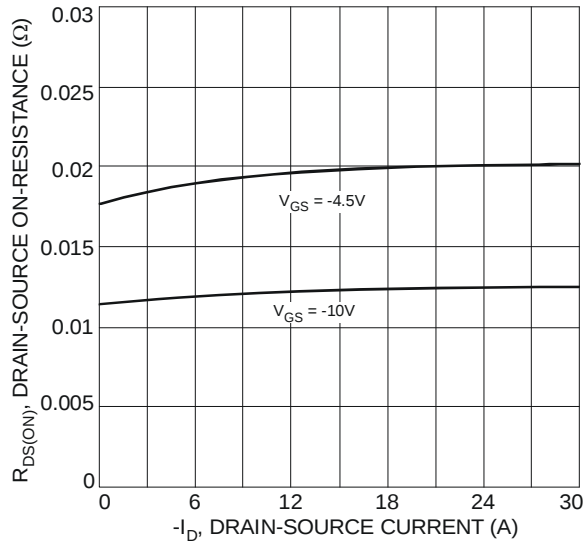


Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

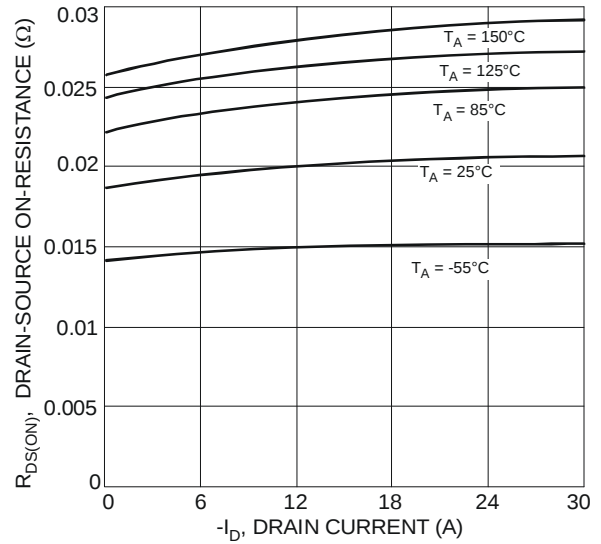


Fig. 4 Typical On-Resistance vs. Drain Current and Temperature

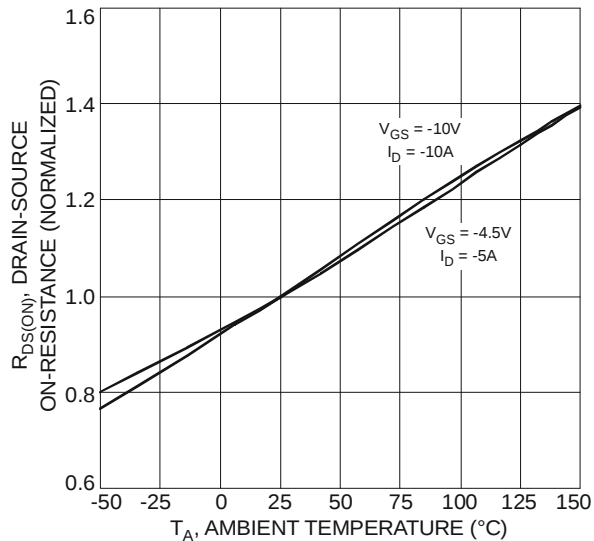


Fig. 5 Normalized On-Resistance vs. Ambient Temperature

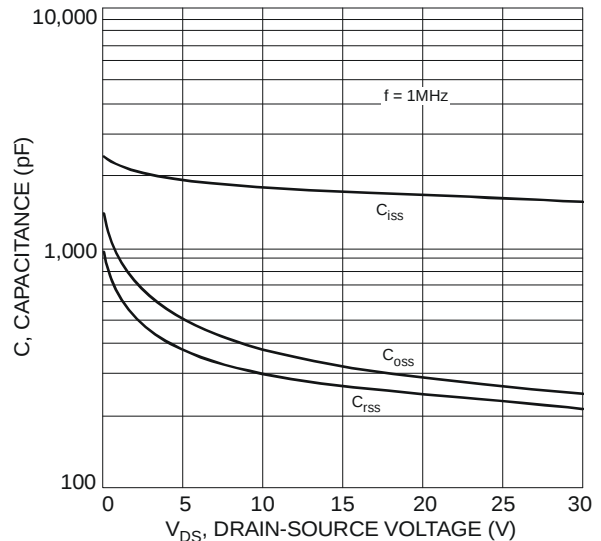


Fig. 6 Typical Total Capacitance

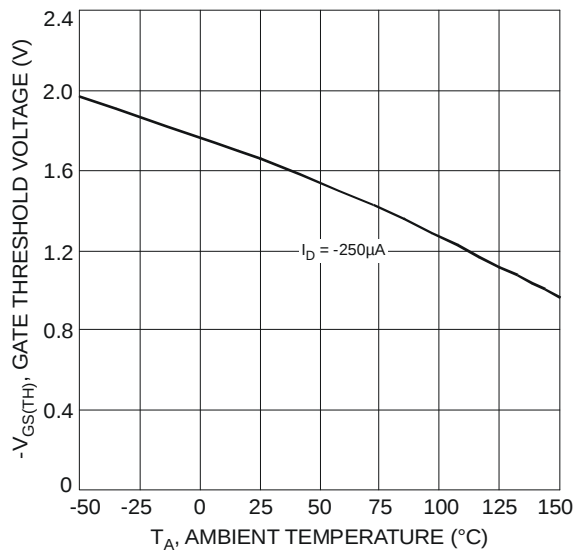


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

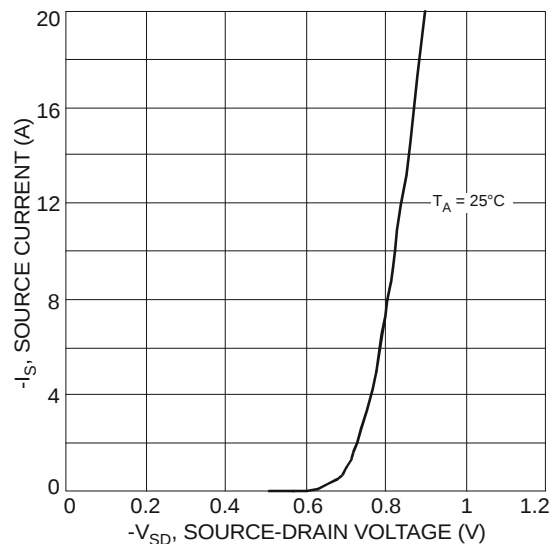


Fig. 8 Diode Forward Voltage vs. Current

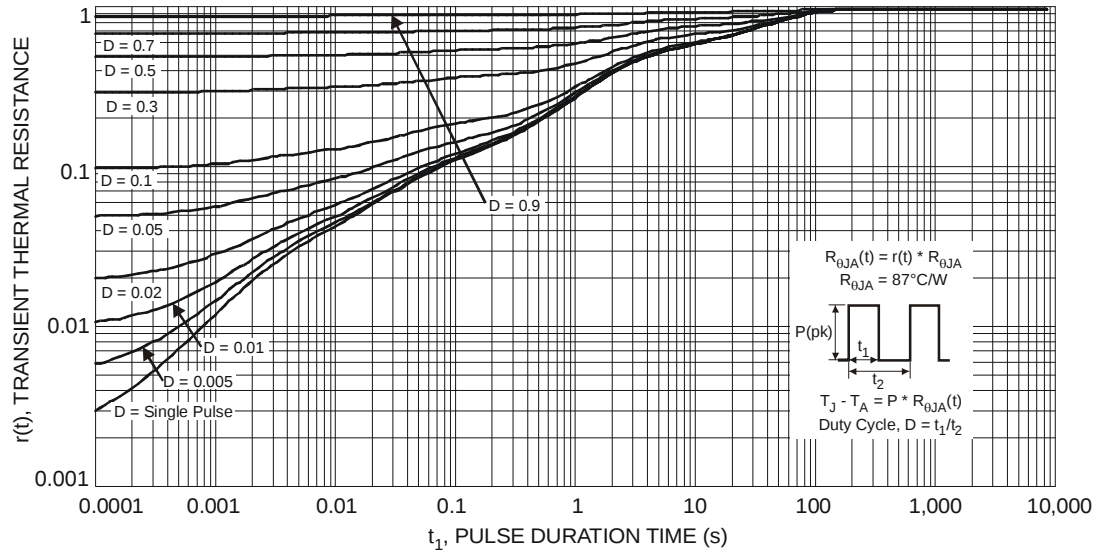


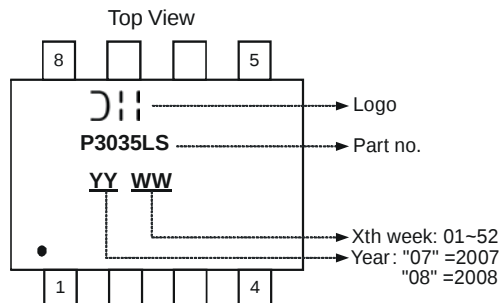
Fig. 9 Transient Thermal Response

Ordering Information (Note 6)

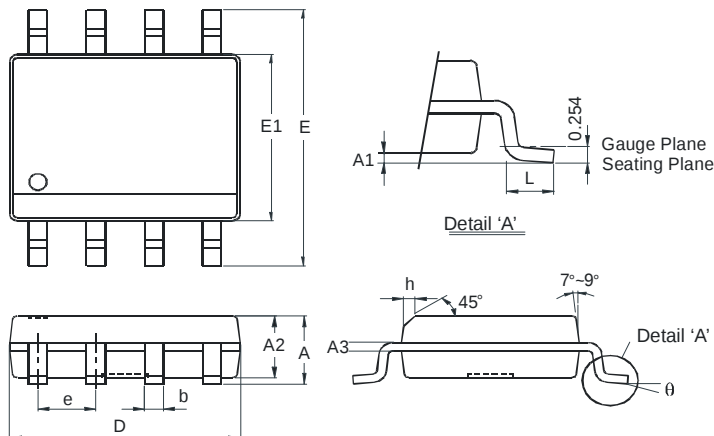
Part Number	Case	Packaging
DMP3035LSS-13	SO-8	2500/Tape & Reel

Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information

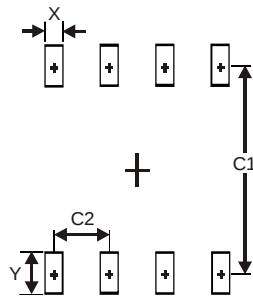


Package Outline Dimensions



SO-8		
Dim	Min	Max
A	-	1.75
A1	0.10	0.20
A2	1.30	1.50
A3	0.15	0.25
b	0.3	0.5
D	4.85	4.95
E	5.90	6.10
E1	3.85	3.95
e	1.27 Typ	
h	-	0.35
L	0.62	0.82
θ	0°	8°
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27

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